

COPY OF PAPERS ORIGINALLY FILED PATENT 81790.0214 (Former Docket No-005702-20068)

8/Election Amoi B 3/26/02 1/8

MINITER UNITED STATES PATENT AND TRADEMARK OFFICE 15 2002

TC 2800 MAIL ROOM

2815

Examiner: J. Fenty

Art Unit:

In re application of:

Tomomi MOMOHARA

Serial No: 09/511,620

Filed: February 23, 2000

For: SEM

SEMICONDUCTOR INTEGRATED

CIRCUIT DEVICE AND METHOD OF

TESTING THE SAME

is being deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed to: Commissioner for Patents, Washington D.C. 20231, on

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Kimberty Yee Name 11/1/01 Date

Signature

RESPONSE TO RESTRICTION REQUIREMENT AND AMENDMENT

Box Non-Fee Amendment Commissioner for Patents Washington, D.C. 20231

Dear Sir:

In response to the Restriction Requirement dated October 2, 2001, Applicants, without traverse, elects for prosecution the claims of Group I, claims 5-8 and 20-40. Furthermore, please amend the above-referenced application as follows:

IN THE SPECIFICATION:

Starting on page 2, line 23, and continuing through page 9, line 23, delete the section of the specification entitled BRIEF SUMMARY OF THE INVENTION, and replace such deleted section with the following replacement section:

"BRIEF SUMMARY OF THE INVENTION

A semiconductor device according to an aspect of the present invention comprises: a semiconductor substrate of a first conductivity type; at least one first well of a second conductivity type formed in the semiconductor substrate; and at least one second well of the first conductivity type formed in at least one first well, wherein the semiconductor device is composed of semiconductor circuits each formed in at least one first well and at least one second well."

